
1N4148

Silicon Epitaxial Planar Diode for Various Detector,
Modulator, Demodulator

HITACHI

ADE-208-147C (Z)

Rev.3
Dec. 2001

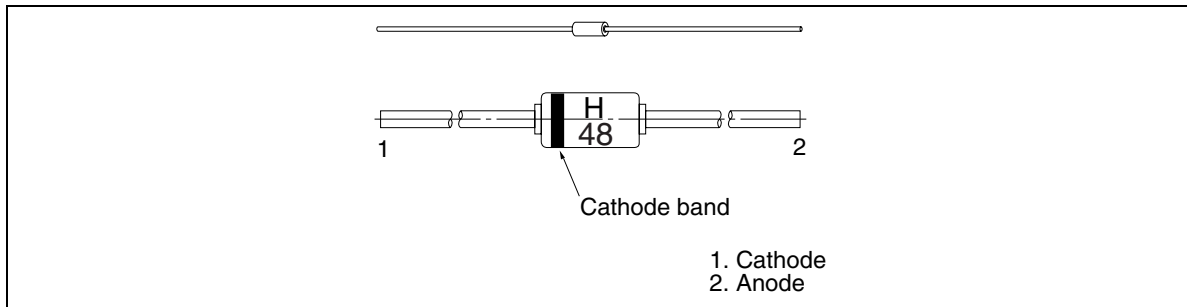
Features

- Low capacitance. ($C = 4.0$ pF max)
- Short reverse recovery time. ($t_r = 4.0$ ns max)
- High reliability with glass seal.

Ordering Information

Type No.	Cathode band	Mark	Package Code
1N4148	Black	H48	DO-35

Outline



1N4148

Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Item	Symbol	Value	Unit
Peak reverse voltage	V_{RM}	100	V
Reverse voltage	V_R	75	V
Peak forward current	I_{FM}	450	mA
Non-Repetitive peak forward surge current	I_{FSM}^*	1	A
Average forward current	I_o	150	mA
Power dissipation	P_d	500	mW
Junction temperature	T_j	200	$^\circ\text{C}$
Storage temperature	T_{stg}	-65 to +200	$^\circ\text{C}$

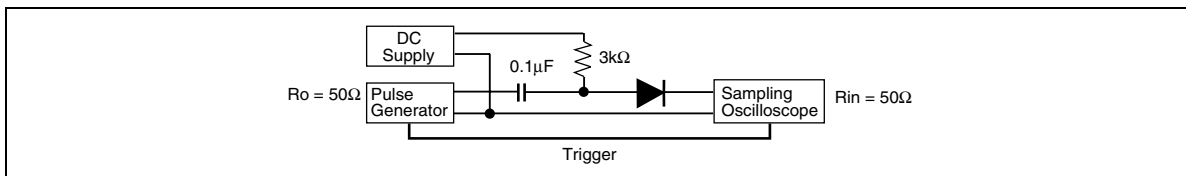
Note: Within 1s forward surge current.

Electrical Characteristics

($T_a = 25^\circ\text{C}$)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Forward voltage	V_F	—	—	1.0	V	$I_F = 10\text{ mA}$
Reverse current	I_R	—	—	25	nA	$V_R = 20\text{ V}$
Capacitance	C	—	—	4.0	pF	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$
Reverse recovery time	t_{rr}^*	—	—	4.0	ns	$I_F = 10\text{ mA}$, $V_R = 6\text{ V}$, $I_{rr} = 1\text{ mA}$, $R_L = 100\ \Omega$

Note: Reverse recovery time test circuit



Main Characteristic

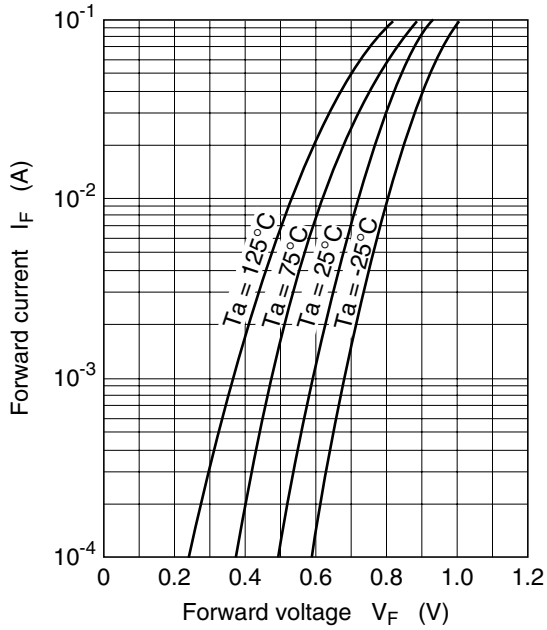


Fig.1 Forward current vs. Forward voltage

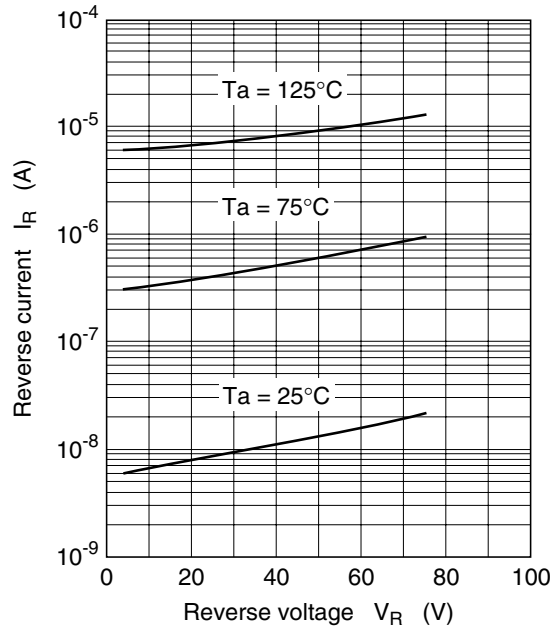


Fig.2 Reverse current vs. Reverse voltage

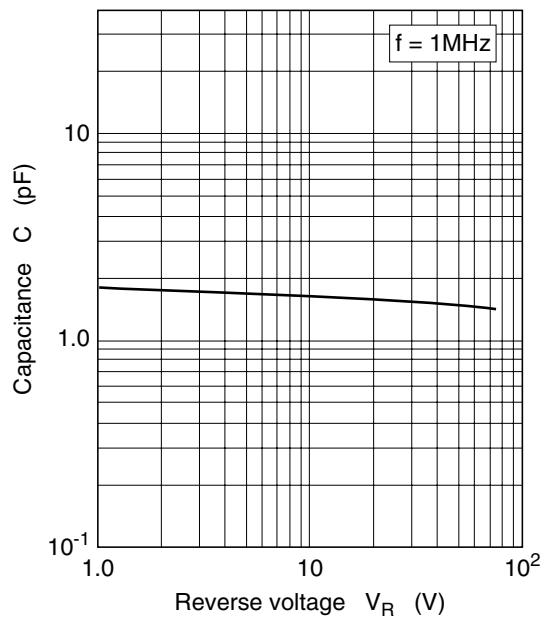
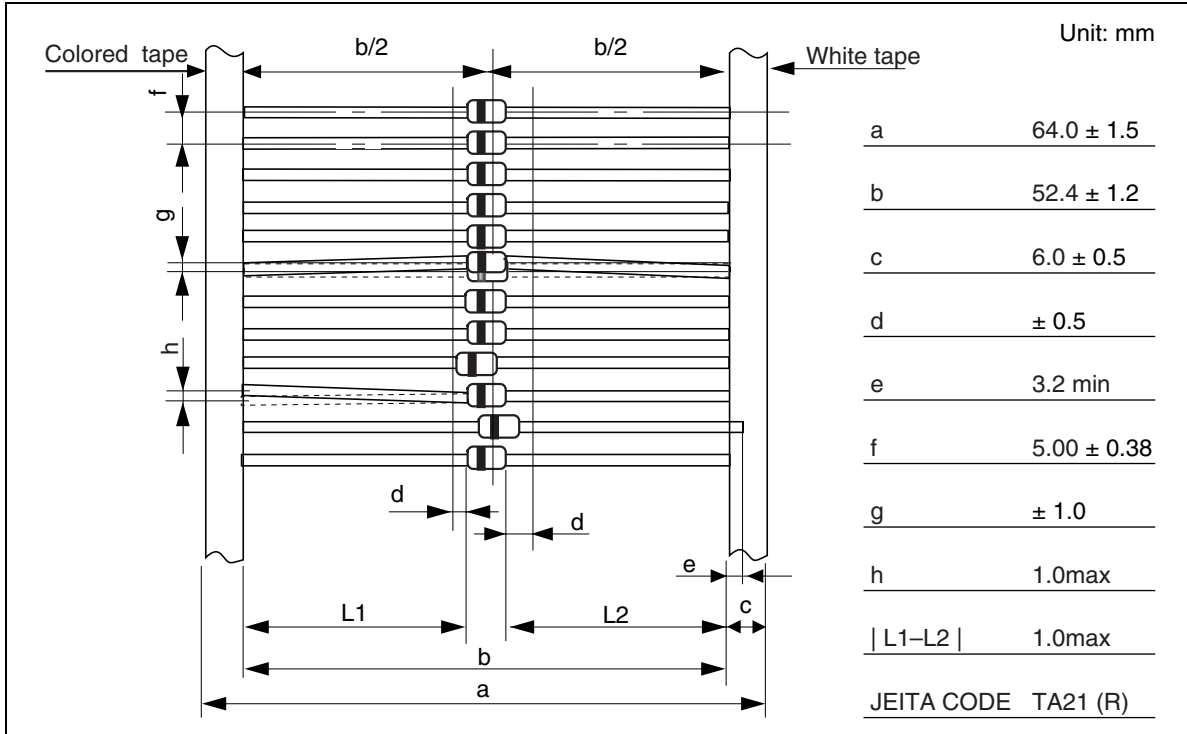


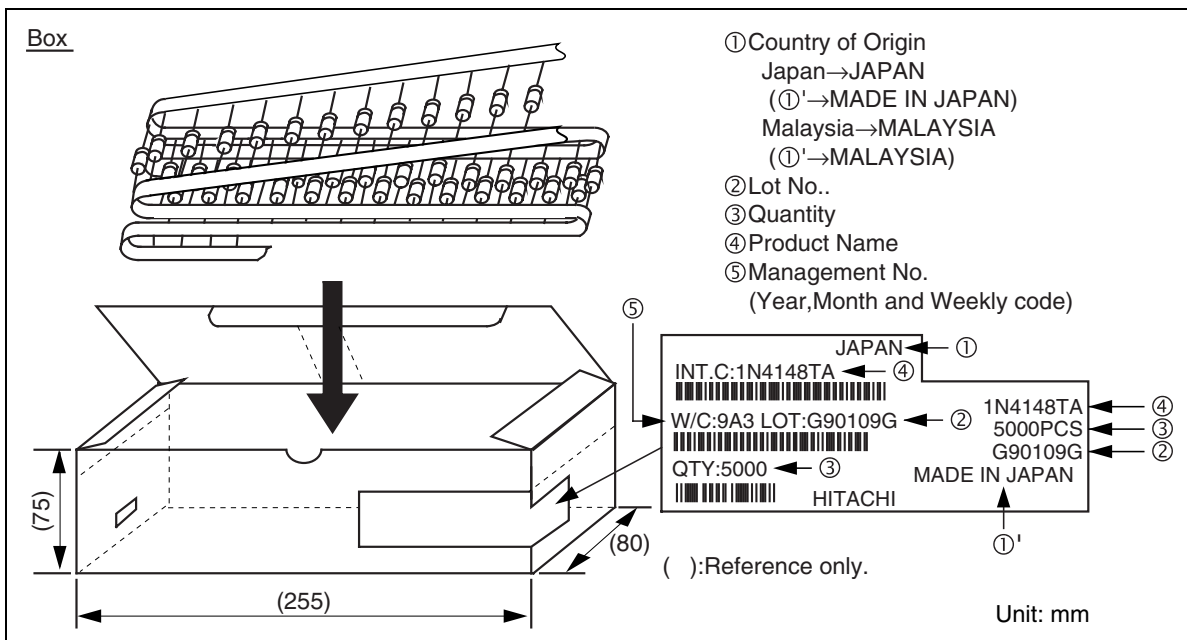
Fig.3 Capacitance vs. Reverse voltage

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Ammo Pack Taping (TA TYPE)

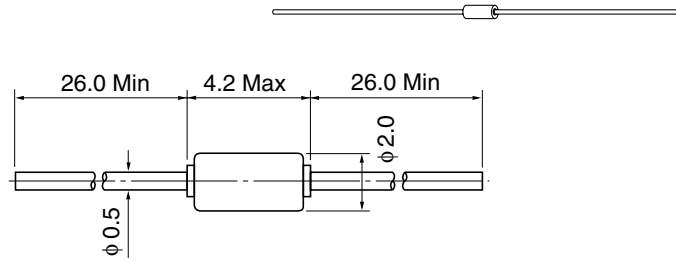


Taping appearance



Package Dimensions

As of July, 2001
Unit: mm



Hitachi Code	DO-35
JEDEC	Conforms
JEITA	Conforms
Mass (reference value)	0.13 g

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